Giant Phonon Softening and Enhancement of Superconductivity by Phosphorus Doping of BaNi₂As₂

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The effects of phosphorus doping on the structural and superconducting phase transitions of BaNi₂($As_{1-x}P_x$)₂ were studied. The specific heat, resistivity, and magnetic susceptibility were measured. The results revealed an abrupt increase in the superconducting transition temperature (T_c) from 0.6 K in the triclinic phase (space group \overline{PI}) with less phosphorus ($x \le 0.067$) to 3.3 K in the tetragonal phase (space group $I4/mmm$) with more phosphorus ($x \ge 0.067$). Our data analysis suggests that a dopinginduced softening related to an in-plane Ni and $As(P)$ phonon mode is responsible for the enhanced superconductivity in the tetragonal phase.

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Superconductivity at high transition temperatures (T_c) is often associated with structural instabilities that are characterized by phonon softening and subsequent structural phase transitions. Enhancement in T_c at a structural phase boundary has been observed in various systems including copper oxides $[1,2]$ $[1,2]$ $[1,2]$ $[1,2]$, iron pnictides $[3,4]$ $[3,4]$ $[3,4]$ $[3,4]$, A15 compounds [\[5\]](#page-3-5), graphite intercalated compounds [[6](#page-3-6)[–9\]](#page-3-7), and elements such as Li and Te under high pressure $[10-16]$ $[10-16]$ $[10-16]$ $[10-16]$. For example, the graphite intercalated compound $CaC₆$ exhibits a gradual increase in T_c from 11.5 to 15.1 K under high pressure followed by a sudden decrease down to \simeq 5 K at 8–10 GPa [\[8\]](#page-3-10). The temperature-dependent resistivity, together with first-principles calculations, suggests that the softening of in-plane Ca vibrations leads to the enhanced T_c and the subsequent phase transition in CaC₆ under high pressure [\[7](#page-3-11)–[9\]](#page-3-7). Tellurium (Te) exhibits a T_c jump from 2.5 to 7.4 K at 32–35 GPa, which is related to the transition from the rhombohedral β -Po structure to the bcc phase [\[14\]](#page-3-12). First-principles calculations suggest that the remarkable increase in T_c can be attributed to a phonon softening of the transverse mode in the bcc phase under high pressure $[14–16]$ $[14–16]$ $[14–16]$. Thus, the tuning of soft phonons appears to be important for maximizing T_c . However, the chemical tuning of soft phonons, which is essential for practical applications, has not yet been fully investigated.

 $BaNi₂As₂$ crystallizes in a tetragonal ThCr₂Si₂-type structure (space group $I4/mmm$) [[17](#page-3-13)[–19\]](#page-3-14). This system exhibits a structural phase transition from a tetragonal to a triclinic phase (space group $\overline{P1}$) at approximately 130 K, below which alternate Ni-Ni bonds (with distances of \simeq 2.8 Å and \simeq 3.1 Å) are formed in the Ni square lattice [\[18\]](#page-3-15). In this triclinic phase, superconductivity, considered to be of the conventional BCS type, emerges at 0.7 K [\[17](#page-3-13)[,19](#page-3-14)[–21\]](#page-3-16). Therefore, this system can be considered a nonmagnetic analogue of iron-based superconductors such as $BaFe₂As₂$. In this Letter, we report that T_c abruptly increases from 0.7 to 3.3 K upon the phosphorus doping of $BaNi₂As₂$. The enhanced superconductivity is accompanied by the triclinic-to-tetragonal phase transition that is induced by phosphorus doping at $x = 0.067$ in $BaNi₂(As_{1-x}P_x)₂$. The specific heat and electrical resistivity suggest that doping-induced phonon softening, related to the in-plane Ni and As vibrations, is responsible for the enhanced superconductivity, demonstrating that the chemical tuning of soft phonons is an effective means to optimize superconductivity.

Single crystals of BaNi₂ $(As_{1-r}P_r)$ ₂ were grown using a self-flux method. A mixture with a ratio of Ba:NiAs:Ni:P = 1:4(1-x):4x:4x was placed in an alumina crucible, sealed in an evacuated quartz tube, heated at $700\degree$ C for 3 h, slowly heated to $1150\degree$ C, and cooled from 1150 to 1000 °C at a rate of 2 °C/h, followed by furnace cooling. Single crystals with a typical dimension of $1 \times 1 \times 0.1$ mm³ were mechanically isolated from the flux. The results of powder x-ray diffraction, performed using a Rigaku RINT-TTR III x-ray diffractometer with CuK_{α} radiation, showed that all specimens are in a single phase. Energy dispersive x-ray spectrometry (EDS) was used to determine the phosphorus content x . Samples with x greater than 0.13 could hardly be obtained by either flux growth or the solid-state reaction, indicating that the solubility limit of P for As is at $x = 0.13$. The samples were treated in a glove box filled with dried Ar gas because they degraded in air within a few days. The magnetization M was measured using a Quantum Design MPMS. The electrical resistivity ρ_{ab} (parallel to the *ab* plane) and specific heat C were measured using a Quantum Design PPMS.

Figure [1](#page-1-0) shows the temperature dependence of the electrical resistivity for BaNi₂($As_{1-x}P_x$)₂. In a manner consistent with previous reports, pure $BaNi₂As₂$ exhibits a

FIG. 1 (color online). Temperature dependence of the electrical resistivity parallel to the ab plane, ρ_{ab} , normalized by the value at 300 K for $BaNi₂(As_{1-x}P_x)₂$. The data measured upon heating and cooling are plotted. For the sake of clarity, ρ_{ab}/ρ_{ab} (300 K) is shifted by 0.175 with respect to all data. T_s is the phase transition temperature at which the tetragonal-to-triclinic phase transition occurs; it is determined as the midpoint of the jump in ρ_{ab} . The residual resistivity ρ_0 ranges from 10 to 30 $\mu\Omega$ cm.

transition at 130 K with a thermal hysteresis accompanying a sudden increase in resistivity upon cooling [\[17–](#page-3-13)[19](#page-3-14)]. For 3.5% phosphorous doping, the transition is significantly suppressed to 90–100 K and the sudden resistivity increase changes into a sudden decrease upon cooling. The transition appears to be absent for 7.7% phosphorous doping. These results suggest the suppression of the triclinic phase at $x \approx 0.07$ in BaNi₂(As_{1-x}P_x)₂.

We found that superconductivity emerges below 3.3 K as soon as the triclinic phase is suppressed with phosphorous doping, while it emerges below 0.7 K in the triclinic phase at $x < 0.07$. This is demonstrated by the low-temperature magnetic susceptibility and resistivity data shown in Fig. [2.](#page-1-1) For $x = 0.070$, the bulk superconductivity is evident from the full shielding diamagnetic signal and sharp resistivity transition at 3.33 K. The superconductivity persists until x reaches the solubility limit at $x = 0.13$, while T_c decreases slightly to 3.24 K. The low-temperature specific-heat data, shown in Figs. $2(c)$ and [3](#page-2-0), give further evidence of the enhanced superconductivity in the tetragonal phase. Pure $BaNi₂As₂$ exhibits a specific heat jump at 0.6 K, as reported previously [\[17–](#page-3-13)[19](#page-3-14)]. The transition temperature increases slightly with phosphorous doping, but remains below 0.97 K as long as the system is in the triclinic phase. In the tetragonal phase with more than 7.7% phosphorous doping, the specific heat jump appears at an elevated temperature of 3.3 K, in a manner consistent with the magnetic and resistivity data.

The enhanced superconductivity at the structural phase boundary in phosphorus-doped $BaNi₂As₂$ is reminiscent

FIG. 2 (color online). (a) Temperature dependences of dc magnetization M measured in a magnetic field H of 30 Oe for BaNi₂($As_{1-x}P_x$)₂ under zero field cooling and field cooling. (b) Temperature dependence of the electrical resistivity parallel to the *ab* plane, ρ_{ab} , normalized by the value at 5 K for $BaNi₂(As_{1-x}P_x)₂$. (c) Temperature dependence of the electronic specific heat divided by the temperature, C_e/T , for BaNi₂(As_{1-x}P_x)₂. C_e was determined by subtracting the phonon contribution βT^3 from the total specific heat C, as shown in Fig. [3.](#page-2-0) The insets show magnified views of the vicinity of the superconducting transition.

of CaC_6 under high pressure $[7-9]$ $[7-9]$ $[7-9]$ $[7-9]$ $[7-9]$ and tellurium at the β -Po bcc phase boundary under high pressure [\[11–](#page-3-17)[16\]](#page-3-9). Mauri *et al.* proposed that the enhanced superconductivity in Te is due to the softening of transverse phonons along the ΓN line in the bcc phase and the resultant enhancement of electron-phonon coupling under pressure [[14](#page-3-12)]. In order to examine the role of soft phonons in the enhanced T_c of phosphorus-doped BaNi₂As₂, the normal-state specific heat was examined at low temperatures. Figure [3](#page-2-0) shows the specific heat divided by the temperature C/T as a function of the squared temperature T^2 . The normalstate data above T_c can be well fitted by $C/T = \gamma + \beta T^2$, where γ is an electronic specific-heat coefficient and β , the coefficient of phonon contributions from which the Debye frequency ω_D is estimated. As can be seen from Fig. [3,](#page-2-0) the slope of the C/T vs T^2 lines is almost unchanged in the triclinic phase for less than 7% phosphorus doping. The slope increases suddenly for 7.7%

FIG. 3 (color online). The specific heat divided by the temperature, C/T , as a function of T^2 for BaNi₂(As_{1-x}P_x)₂. The broken lines denote the fits by $C/T = \gamma + \beta T^2$, where γ is the electronic specific heat coefficient and β is a constant corresponding to the Debye phonon contributions.

phosphorous doping, suggesting the occurrence of significant phonon softening when the triclinic-to-tetragonal phase transition occurs. The slope decreases upon further phosphorous doping in the tetragonal phase. Figure $4(c)$ shows the estimated Debye frequency ω_D as a function of the phosphorus content x. ω_D shows a significant reduction from 250 to 150 K at the structural phase boundary of $x = 0.07$.

In contrast to the strong dependence of both ω_D and T_c on doping, the electronic specific-heat coefficient γ (\simeq 14 mJ/mol K²) is almost independent of the phosphorus content x , as can be seen from the almost unchanged intercept of the C/T vs T^2 lines along the C/T axis in Fig. [3.](#page-2-0) Furthermore, the electronic density of states at the Fermi level $\simeq 6$ eV⁻¹ per formula unit, as determined from the specific heat γ , is comparable to the band calculation value 3.57 eV^{-1} for the tetragonal phase of pure BaNi₂As₂ [\[20\]](#page-3-18). These observations suggest that the structural phase transition, as well as the enhanced superconductivity in the tetragonal phase, is not electronic but phononic, specifically, enhanced electron-phonon coupling due to soft phonons, in origin [\[22\]](#page-3-19). Indeed, the normalized specific heat jump $\Delta C/\gamma T_c \simeq 1.3$ for the triclinic phase at $x \le 0.07$, determined from the data shown in Fig. [2\(c\)](#page-1-2), is comparable to the value of the weak coupling limit (= 1.43), while $\Delta C/\gamma T_c$ is enhanced in the tetragonal phase with a maximum value of 1.90 at $x = 0.077$, indicative of strong coupling superconductivity. $\Delta C/\gamma T_c$ is gradually decreased upon further doping to 1.78 and 1.60 for $x = 0.092$ and 0.104, respectively, as can be seen from Fig. $2(c)$ [[23](#page-4-0)]. We estimate the logarithmicaveraged phonon frequency ω_{\ln} using the relationship for strong-coupling superconductors $\Delta C(T_c)/\gamma T_c$ = 1.43[1 + (53/x²) ln(x/3)], where $x = \omega_{\text{ln}}/T_c$ [[24](#page-4-1)[–26\]](#page-4-2).

FIG. 4 (color online). (a) Lattice parameters a and c as a function of phosphorous content x at 300 K for $BaNi_2(As_{1-r}P_r)$. (b) Electronic phase diagram of $BaNi₂(As_{1-x}P_x)₂$. The (blue) closed circles represent the superconducting transition temperatures T_c . For clarity, the values of T_c have been scaled by a factor of 10. SC1 and SC2 denote the superconducting phases. The (red) open and closed diamonds represent the tetragonal-to-triclinic structural transition temperatures T_s upon cooling and heating, respectively. The insets show schematic views of Ni planes in the triclinic and tetragonal phase. (c) The frequency ω_D and the logarithmic-averaged phonon frequency ω_{\ln} as a function of phosphorous content x for BaNi₂(As_{1-x}P_x)₂. ω_{ln} was determined from the normalized specificheat jump in Fig. $2(c)$ and ω_D was determined from the slope of the C/T vs T^2 curves in Fig. [3.](#page-2-0)

Figure $4(c)$ shows ω_{\ln} , together with the Debye frequency ω_D , as a function of the phosphorus content x. Both ω_{\ln} and ω_D exhibit significant softening as the system approaches the structural phase boundary from the tetragonal side, suggesting that the low-lying soft phonons, which are coupled strongly with acoustic modes, play an important role in the emergence of the strong-coupling superconductivity in the tetragonal phase. The in-plane Ni and As mode at $\sim 50 \text{ cm}^{-1}$ (equivalent to 80 K) [\[20\]](#page-3-18), which is thought to be quenched to form alternating Ni-As bonds in the triclinic phase, could be a soft mode, although further experimental confirmations of the same are required from inelastic neutron scattering and ultrasonic experiments.

Our results are summarized in the electronic phase diagram shown in Fig. [4\(b\).](#page-2-1) The triclinic phase transition temperature in pure $BaNi₂As₂$ is strongly suppressed with phosphorus doping. As a result, the superconducting transition temperature is enhanced from $T_c = 0.6{\text -}0.9 \text{ K}$ in the triclinic phase to 3.2–3.3 K in the tetragonal phase. A similar stepwise shape of the superconducting phase boundary, where another structural phase boundary intersects, has been observed in tellurium under high pressure $[14]$. A similar mechanism may be active in the phosphorous-doped $BaNi₂As₂$. Phosphorous is isovalent with arsenic, but has a smaller ionic radius. Therefore, phosphorous doping serves to create chemical pressure. Indeed, lattice parameters a and c at 300 K show monotonic dependence on the phosphorus content x , as shown in Fig. $4(a)$; thus, the unit cell volume decreases monotonically from 199.9 \AA^3 for pure BaNi₂As₂ to 198.1 \AA^3 for 13% phosphorus doping of BaNi₂($As_{1-x}P_x$)₂. Soft phonons in the tetragonal phase, indicated by both ω_D and ω_{\ln} , shown in Fig. [4\(c\)](#page-2-1), could enhance the electron-phonon coupling and thus the superconductivity [[22](#page-3-19)]. When the phosphorus content x is decreased from the tetragonal side, the soft phonon leads to a structural instability and eventually results in the triclinic phase transition and suppressed superconductivity. There exists a miscibility gap of the phosphorus content above $x = 0.13$. It should be noted that superconductivity below $T_c = 3$ K appears when arsenic is completely replaced by phosphorus in $BaNi_2P_2$ [[27](#page-4-3)].

To conclude, our experiments show that the enhancement of superconductivity associated with phonon softening and subsequent structural phase transition occurs because of the phosphorus doping of $BaNi₂As₂$. Specifically, the increase in T_c from 0.6 to 3.3 K (approximately fivefold enhancement) is related to the giant phonon softening of approximately 50% at the triclinic-to-tetragonal phase transition induced by phosphorus doping. Our results demonstrate that the chemical tuning of soft phonons is practical and effective for optimizing superconductivity.

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the material parameters of $BaNi₂As₂$ are in the range where $\langle \omega \rangle$ is larger than $\left(\frac{C}{2M}\right)^{1/2}$, and thus, the λ term dominates the ω dependence of T_c . See W. L. McMillan, Phys. Rev. 167[, 331 \(1968\).](http://dx.doi.org/10.1103/PhysRev.167.331)

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